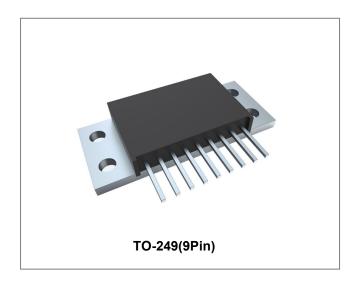






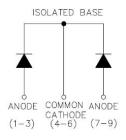
153CMQ135/153CMQ150 SCHOTTKY RECTIFIER



Features

- 175 °C T_J operation
- Isolated heatsink
- Multiple leads per terminal for high frequency, high current PC board mounting
- Low profile, high current package
- Center tap module
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Base plate: Nickel plated; Terminals: Nickel plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Schematic & Pin Configuration



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.		Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	$V_{RRM} \ V_{RWM}$		135	159CMQ135	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
DC Blocking Voltage	V _{RWM} V _R	-	150	159CMQ150	
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _C =90°C, rectangular wave form	75(Per Leg) 150(Per Device)		Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	864		Α

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •







Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Peg Leg)*	V _{F1}	@80A, Pulse, T _J = 25 °C	0.89	1.05	V
	V _{F2}	@80A, Pulse, T _J = 125 °C	0.77	0.85	V
Reverse Current(Peg Leg)*	I _{R1}	@V _R = rated V _R ,T _J = 25 °C	0.02	1.5	mA
	I _{R2}	@V _R = rated V _R ,T _J = 125 °C	1	21	mA
Junction Capacitance(Peg Leg)	Ст	$@V_R = 5V, T_C = 25 \text{ °C}$ $f_{SIG} = 1MHz$	1000	1300	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

^{*} Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +175	°C
Storage Temperature	T _{stg}	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case (Per Leg)	R _θ JC	DC operation	1.0	°C/W
Typical Thermal Resistance Junction to Case (Per Package)	R _{θJC}	DC operation	0.50	°C/W
Typical Thermal Resistance, case to Heat Sink	R _{θcs}	Mounting surface, smooth and greased	0.10	°C/W
Mounting Torque	T _M	-	40(min)	Va om
			58(max)	Kg-cm
Approximate Weight	wt	-	61	g
Case Style	TO-249(9 pin)			



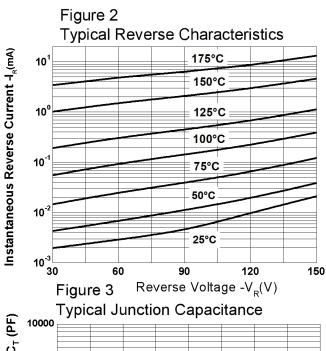


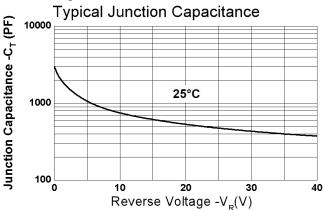


Ratings and Characteristics Curves

Figure1
Typical Forward Characteristics

10²
175°C
125°C
125°C
10⁰
0.3 0.5 0.7 0.9 1.1
Forward Voltage -V_F(V)





Ordering Information

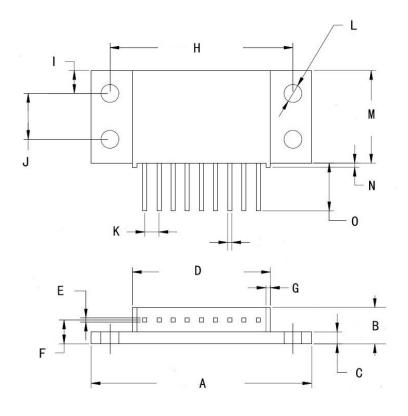
Device	Package	Shipping	
159CMQ SERIES	TO-249(Pb-Free)	24pcs/ box	





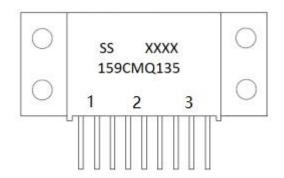


Mechanical Dimensions TO-249(9pin) (Inches/Millimeters)



CVMPOL	Millimeters		Inches		
SYMBOL	Min.	Max.	Min.	Max.	
Α	60.38	61.58	2.377	2.424	
В	8.38	10.16	0.330	0.400	
С	2.77	3.57	0.109	0.141	
D	37.00	38.20	1.457	1.504	
E	0.62	1.32	0.024	0.052	
F	6.35		0.250		
G	1.27		0.050		
Н	50.80		2.000		
I	6.35		0.250		
J	12.70		0.500		
K	3.38	4.23	0.133	0.167	
L	4.35	5.05	0.171	0.199	
М	24.90	25.90	0.980	1.020	
N	0.64	1.26	0.025	0.050	
0	11.80	13.51	0.465	0.532	
Р	0.69	1.34	0.027	0.053	

Marking Diagram



Where XXXX is YYWW

1st row SS YYWW
2nd row 159CMQ135
3rd row 1 2 3 (pin)
SS = SS
YY = Year
WW = Week

Cautions: Molding resin

Epoxy resin UL:94V-0

159CMQ...SERIES



Technical Data Data Sheet N1182, Rev. A





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